

/ Descriptions

SOT-89 NPN Silicon NPN transistor in a SOT-89 Plastic Package.

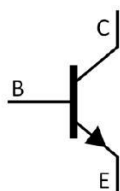
/ Features

$V_{CE(sat)}$, h_{FE}
Low saturation voltage, excellent h_{FE} linearity and high h_{FE} . HF Product.

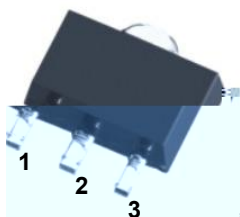
/ Applications

3
Output stage of 3 watts audio amplifier, voltage regulator, DC-DC converter and relay driver.

/ Equivalent Circuit



/ Pinning



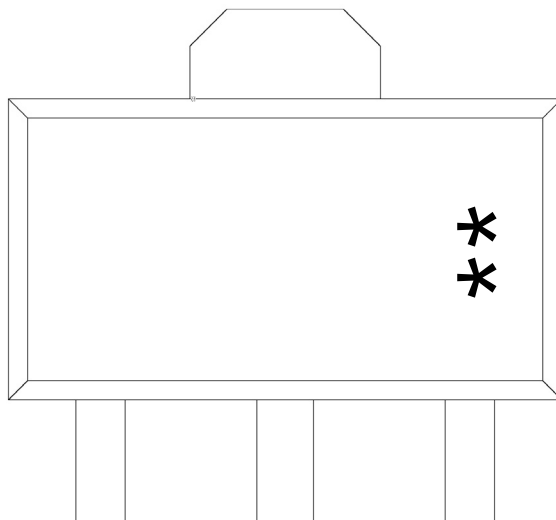
PIN1 Base PIN 2 Collector PIN 3 Emitter

/ Marking

h_{FE} Classifications Symbol	R	Q	P	E
h_{FE} Range	60 120	100 200	160 320	200 400
Marking	H82R	H82Q	H82P	H82E

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	40	V
Collector to Emitter Voltage	V_{CEO}	30	V
Emitter to Base Voltage	V_{EBO}	5.0	V
Collector Current-Continuous	I_C	3.0	A
Collector Power Dissipation	P_C	500	mWV

/ Marking Instructions



H

82

R h_{FE}

**

Note:

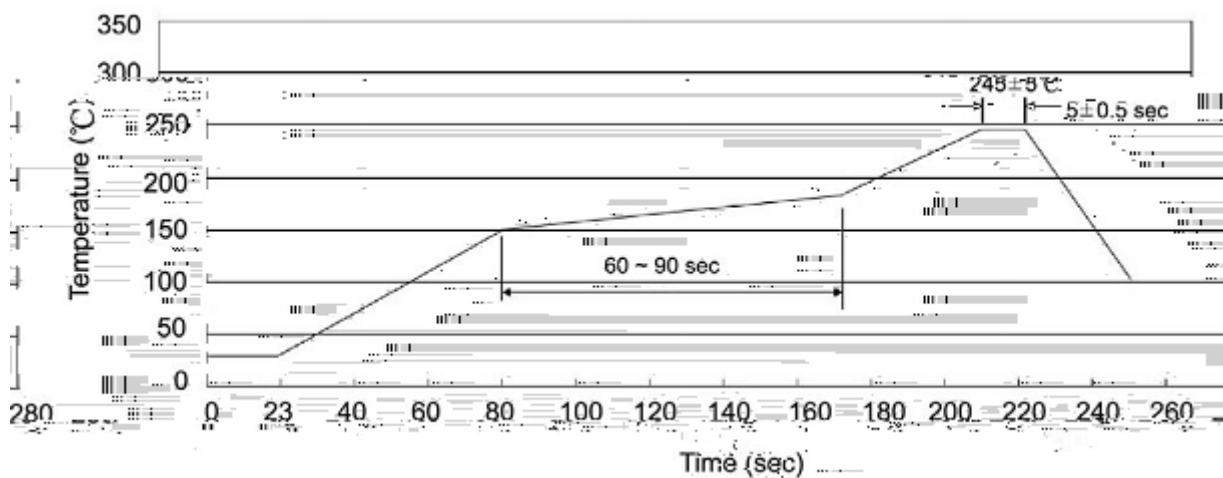
H: Company Code.

82: Product Type.

R h_{FE} Classifications Symbol

**: Lot No. Code, code change with Lot No.

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Note:

- | | | | | | |
|---|-------|-----|-----------|--------|---|
| 1 | 25 | 150 | 60 | 90sec; | 1.Preheating:25~150 , Time:60~90sec. |
| 2 | 245±5 | | 5±0.5sec; | | 2.Peak Temp.:245±5 , Duration:5±0.5sec. |
| 3 | | 2 | 10 | /sec. | 3. Cooling Speed: 2~10 /sec. |

/ Resistance to Soldering Heat Test Conditions

260±5 10±1 sec. Temp.:260±5 Time:10±1 sec

/ Packaging SPEC.

/ REEL

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	只 卷盘	卷盘 盒	只 盒	盒 箱	只 箱		盒	箱

/ Notices